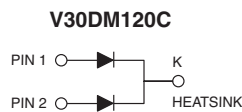
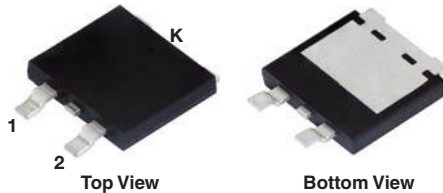


## Dual Trench MOS Barrier Schottky Rectifier

 Ultra Low  $V_F = 0.51\text{ V}$  at  $I_F = 5\text{ A}$ 
**TMBS® eSMP® Series**  
**TO-263AC (SMPD)**

**RoHS**  
 COMPLIANT  
 HALOGEN  
**FREE**

### FEATURES

- Trench MOS Schottky technology
- Very low profile - typical height of 1.7 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- AEC-Q101 qualified available:
  - Automotive ordering code: base P/NHM3
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)

### TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, industrial, and automotive application.

### MECHANICAL DATA

**Case:** TO-263AC SMPD

Molding compound meets UL 94 V-0 flammability rating  
 Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

**Polarity:** As marked

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 15 A
$V_{RRM}$	120 V
$I_{FSM}$	150 A
$V_F$ at $I_F = 15\text{ A}$ ( $T_A = 125\text{ °C}$ )	0.67 V
$T_J$ max.	150 °C
Package	TO-263AC (SMPD)
Diode variations	Dual common cathode

MAXIMUM RATINGS ( $T_A = 25\text{ °C}$ unless otherwise noted)			
PARAMETER	SYMBOL	V30DM120C	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	120	V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$	per device	30
		per diode	15
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	$I_{FSM}$	150	A
Voltage rate of change (rated $V_R$ )	$dV/dt$	10 000	V/ $\mu$ s
Operating junction and storage temperature range	$T_J, T_{STG}$	-40 to +150	°C



ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.59	-	V
	I <sub>F</sub> = 7.5 A			0.66	-	
	I <sub>F</sub> = 15 A			0.88	0.97	
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.51	-	
	I <sub>F</sub> = 7.5 A			0.56	-	
	I <sub>F</sub> = 15 A			0.67	0.76	
Reverse current per diode	V <sub>R</sub> = 90 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	5	-	μA
		T <sub>A</sub> = 125 °C		3.1	-	mA
	V <sub>R</sub> = 120 V	T <sub>A</sub> = 25 °C		-	800	μA
		T <sub>A</sub> = 125 °C		6	27	mA

**Notes**

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width ≤ 5 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)			
PARAMETER	SYMBOL	V30DM120C	UNIT
Typical thermal resistance	per diode	R <sub>θJC</sub>	2.2
	per device		1.2
	per device	R <sub>θJA</sub> <sup>(1)(2)</sup>	48

**Notes**

- (1) The heat generated must be less than the thermal conductivity from junction-to-ambient: dP<sub>D</sub>/dT<sub>J</sub> < 1/R<sub>θJA</sub>
- (2) Free air, without heatsink

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-263AC (SMPD)	V30DM120C-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel
TO-263AC (SMPD)	V30DM120CHM3/I <sup>(1)</sup>	0.55	I	2000/reel	13" diameter plastic tape and reel

**Note**

- (1) AEC-Q101 qualified

**RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)**

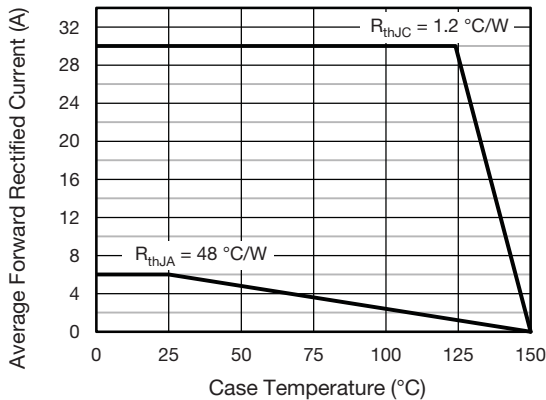


Fig. 1 - Forward Current Derating Curve

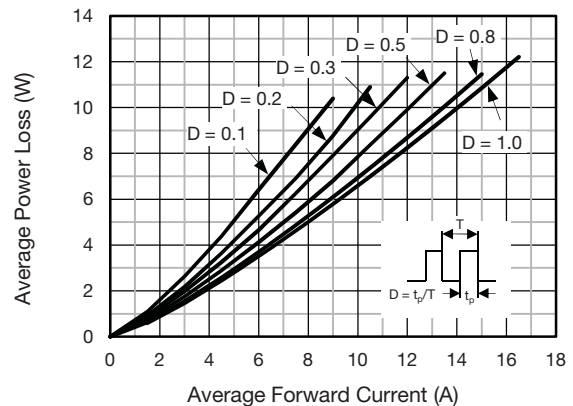


Fig. 2 - Forward Power Loss Characteristics Per Diode

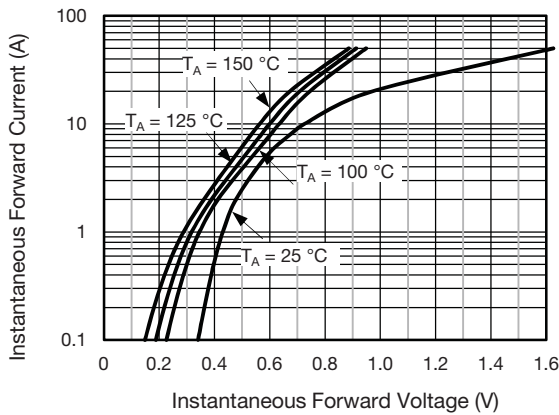


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

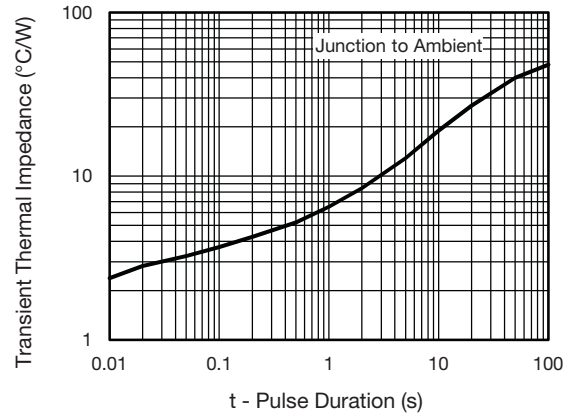


Fig. 6 - Typical Transient Thermal Impedance Per Device

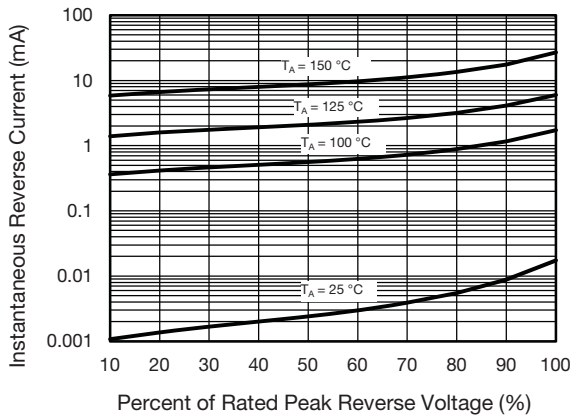


Fig. 4 - Typical Reverse Characteristics Per Diode

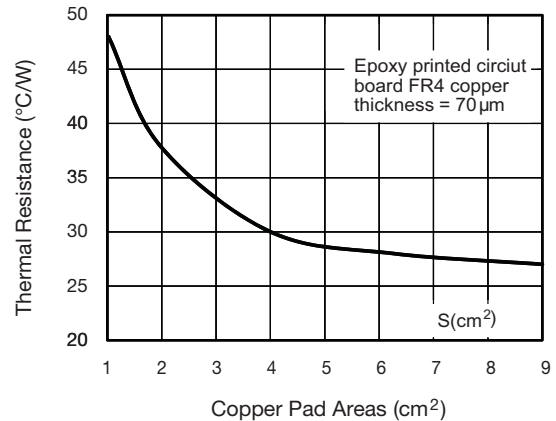


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

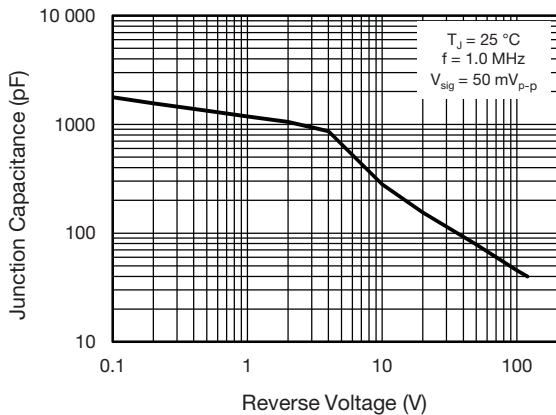
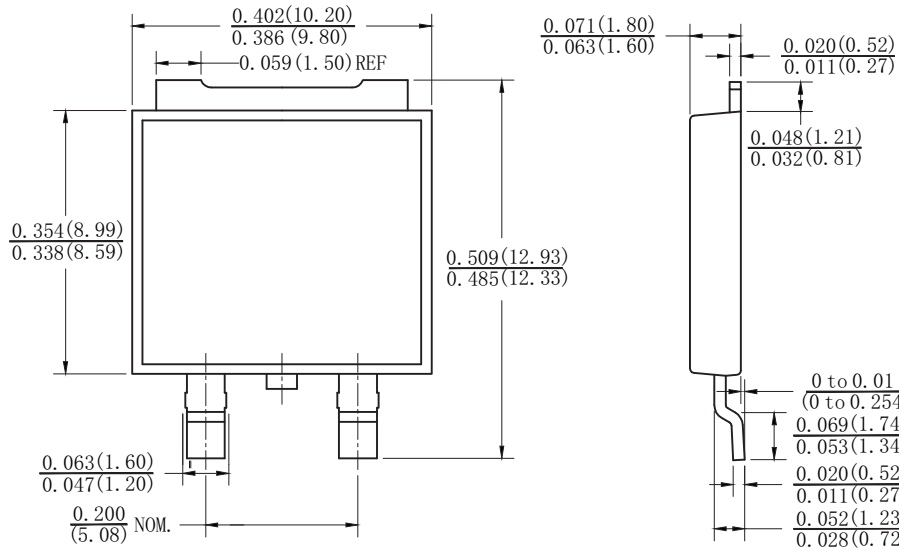


Fig. 5 - Typical Junction Capacitance Per Diode

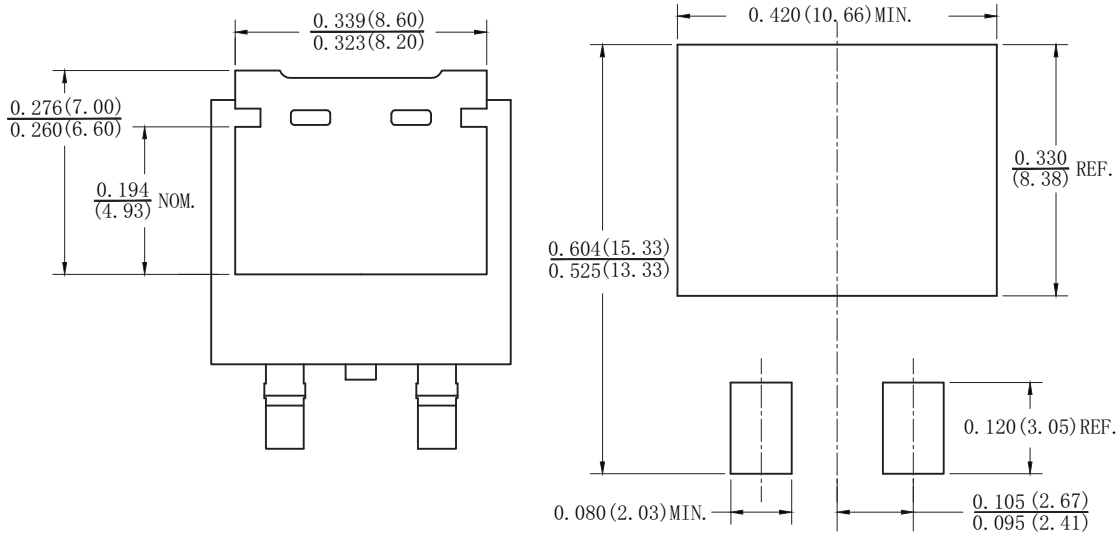


## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

### TO-263AC (SMPD)



### Mounting Pad Layout





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